

### 1.0 Features

- PrimAccurate<sup>™</sup> primary-side feedback eliminates optoisolators and simplifies design
- Internal 800-V bipolar junction transistor (BJT)
- Dynamic base current control
- Optimized 72kHz maximum PWM switching frequency achieves best size and efficiency
- No-load power consumption < 30mW at 230V<sub>AC</sub> with typical application circuit
- Fast dynamic load response for both one-time and repetitive load transients
- Adaptive multi-mode PWM/PFM control improves efficiency
- Quasi-resonant operation for highest overall efficiency
- Low EMI design enhances manufacturability
- Very tight constant voltage and constant current regulation with primary-side-only feedback
- No external loop compensation components required
- Complies with EPA 2.0 energy efficiency specifications with ample margin
- Built-in soft start
- Built-in protections for output short-circuit, output low impedance, and output overvoltage
- Built-in over-temperature protection (OTP)
- No audible noise over entire operating range

### 2.0 Description

The CR1511 is a high performance AC/DC power supply control device that uses digital control technology to build peak current mode PWM flyback power supplies. This device includes an internal power BJT and operates in quasi-resonant mode to provide high efficiency along with a number of key built-in protection features, while minimizing the external component count, simplifying EMI design, and lowering the total bill of material cost. The CR1511 removes the need for secondary feedback circuitry while achieving excellent line and load regulation. It also eliminates the need for loop compensation components while maintaining stability in all operating conditions. The pulse-by-pulse waveform analysis allows for a loop response that is much faster than traditional solutions, resulting in improved dynamic load response for both one-time and repetitive load transients. The built-in current limit function enables optimized transformer design in universal off-line applications and allows for a wide input voltage range.

Dialog's innovative proprietary technology ensures that power supplies built with the CR1511 can achieve the highest average efficiency, less than 30mW no-load power consumption, and fast dynamic load response in a compact form factor.

## 3.0 Applications

- Low-power AC/DC power supply for smart meters, motor control, industrial, and home appliances applications
- 5V applications such as phone chargers/adapters



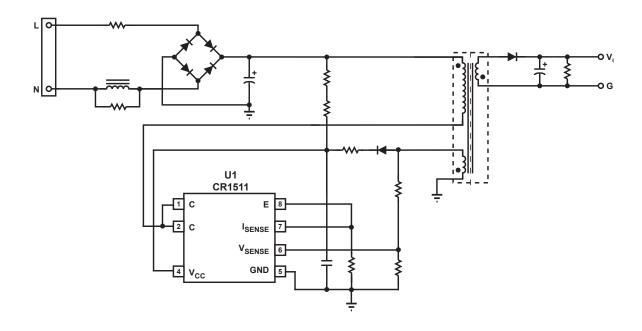


Figure 3.1: CR1511 Typical Application Circuit

#### **WARNING:**

The CR1511 is intended for high voltage AC/DC offline applications. Contact with live high voltage offline circuits or improper use of components may cause lethal or life threatening injuries or property damage. Only qualified professionals with safety training and proper precaution should operate with high voltage offline circuits.

### CR1511 Output Power Table at Universal Input (85V<sub>AC</sub>-264V<sub>AC</sub>)

| Condition       | Adapter <sup>1</sup> | Open Frame <sup>2</sup> |
|-----------------|----------------------|-------------------------|
| Output Power(W) | 4.0                  | 5.0                     |

#### Notes:

- 1. Maximum practical continuous output power measured at enclosure internal ambient temperature of 60°C and device emitter pin (pin 8) temperature of ≤ 90°C (adapter is placed in a non-ventilated environment).
- 2. Maximum practical continuous output power measured at open frame ambient temperature of 50°C and device emitter pin (pin 8) temperature of ≤ 90°C while minimum bulk capacitor voltage is kept above 90V and no special heatsinking is used (test unit is placed in a non-ventilated environment).
- 3. The output power can vary depending on the power supply system designs and operating conditions.





## **4.0 Pinout Description**

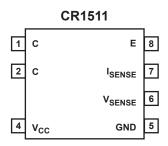


Figure 4.1: 7-Lead SOIC Package

| Pin# | Name               | Туре          | Pin Description  |
|------|--------------------|---------------|--|
| 1    | С                  | BJT Collector | Collector of internal BJT.   |
| 2    | С                  | BJT Collector | Collector of internal BJT.   |
| 4    | $V_{CC}$           | Power Input   | Power supply for control logic .   |
| 5    | GND                | Ground        | Ground.  |
| 6    | $V_{SENSE}$        | Analog Input  | Auxiliary Voltage sense (used for primary-side regulation).                            |
| 7    | I <sub>SENSE</sub> | Analog Input  | Primary current sense. Used for cycle-by-cycle peak current control and current limit. |
| 8    | E                  | BJT Emitter   | Emitter of internal BJT (pin 7 and pin 8 must be shorted on PCB).                      |



### **5.0 Absolute Maximum Ratings**

Absolute maximum ratings are the parameter values or ranges which can cause permanent damage if exceeded. For maximum safe operating conditions, refer to Electrical Characteristics in Section 7.0. ( $T_A = 25^{\circ}$ C, unless otherwise noted). Proper design precautions must be made to ensure that the internal die junction temperature of the iW1816 does not exceed 150°C. Otherwise permanent damage to the device may occur.

| Parameter   | Symbol             | Value       | Units |
|---|--------------------|-------------|-------|
| DC supply voltage range (pin 4, I <sub>CC</sub> = 20mA max)   | V <sub>cc</sub>    | -0.3 to 25  | V     |
| Continuous DC supply current at $V_{CC}$ pin ( $V_{CC}$ = 15V)  | I <sub>cc</sub>    | 20          | mA    |
| V <sub>SENSE</sub> input (pin 6, I <sub>Vsense</sub> ≤ 10mA)  |                    | -0.7 to 4.0 | V     |
| I <sub>SENSE</sub> input (pin 7)  |                    | -0.3 to 4.0 | V     |
| ESD rating per JEDEC JESD22-A114  |                    | 2,000       | V     |
| Collector-Emitter breakdown voltage (Emitter and base shorted together; $I_C = 1$ mA, $R_{EB} = 0$ Ω) | V <sub>CES</sub>   | 800         | V     |
| Collector current <sup>1</sup>  | I <sub>C</sub>     | 1.5         | А     |
| Collector peak current¹ (t <sub>p</sub> < 1ms)  | I <sub>CM</sub>    | 3           | А     |
| Maximum junction temperature  | T <sub>J MAX</sub> | 150         | °C    |
| Storage temperature   | T <sub>STG</sub>   | -55 to 150  | °C    |
| Lead temperature during IR reflow for ≤ 15 seconds  | T <sub>LEAD</sub>  | 260         | °C    |

### **6.0 Thermal Characteristics**

| Parameter   | Symbol                | Value | Units |  |
|---|-----------------------|-------|-------|--|
| Thermal Resistance Junction-to-Ambient <sup>1</sup>               | $\theta_{JA}$         | 132   | °C/W  |  |
| Thermal Resistance Junction-to-GND pin (pin 5) <sup>2</sup>       | $\Psi_{JB}$           | 71    | °C/W  |  |
| Thermal Resistance Junction-to-Collector pin (pin 1) <sup>2</sup> | $\psi_{\text{J-BJT}}$ | 49    | °C/W  |  |
| Thermal Shutdown Threshold <sup>3</sup>                           | T <sub>SD</sub>       | 150   | °C    |  |
| Thermal Shutdown Recovery³  | T <sub>SD-R</sub>     | 100   | °C    |  |

#### Notes:

- 1.  $\theta_{JA}$  is measured in a one-cubic-foot natural convection chamber.
- 2. ψJB [Psi Junction to Board] provides an estimation of the die junction temperature relative to the PCB [Board] surface temperature. ψJ-BJT [Psi Junction to Collector pin] provides an estimation of the die junction temperature relative to the collector pin [internal BJT Collector] surface temperature. ψJB is measured at the ground pin (pin 5) without using any thermal adhesives. See Section 10.14 for more information.
- 3. These parameters are typical and they are guaranteed by design.





### 7.0 Electrical Characteristics

 $V_{CC}$  = 12V, -40°C  $\leq$  T<sub>A</sub>  $\leq$  85°C, unless otherwise specified (Note 1)

| Parameter  | Symbol                  | Test Conditions                                 | Min   | Тур   | Max   | Unit |
|--|-------------------------|---|-------|-------|-------|------|
| V <sub>SENSE</sub> SECTION (Pin 6)                 |                         |   |       |       |       |      |
| Input leakage current                              | I <sub>BVS</sub>        | V <sub>SENSE</sub> = 2V                         |       |       | 1     | μA   |
| Nominal voltage threshold                          | V <sub>SENSE(NOM)</sub> | TA=25°C, negative edge                          | 1.521 | 1.536 | 1.551 | V    |
| Output OVP threshold                               | V <sub>SENSE(MAX)</sub> | TA =25°C, negative edge                         | 1.786 | 1.880 | 1.974 | V    |
| I <sub>SENSE</sub> SECTION (Pin 7)                 |                         |   |       | •     |       |      |
| Overcurrent threshold                              | V <sub>OCP</sub>        |   | 1.11  | 1.15  | 1.19  | V    |
| I <sub>SENSE</sub> regulation upper limit (Note 1) | V <sub>IPK(HIGH)</sub>  |   |       | 1.0   |       | V    |
| I <sub>SENSE</sub> regulation lower limit (Note 1) | V <sub>IPK(LOW)</sub>   |   |       | 0.23  |       | V    |
| Input leakage current                              | I <sub>LK</sub>         | I <sub>SENSE</sub> = 1.0V                       |       |       | 1     | μA   |
| V <sub>CC</sub> SECTION (Pin 4)                    |                         |   |       | •     |       |      |
| Maximum operating voltage (Note1)                  | $V_{CC(MAX)}$           |   |       |       | 20    | V    |
| Start-up threshold                                 | V <sub>CC(ST)</sub>     | V <sub>CC</sub> rising                          | 10    | 11    | 12    | V    |
| Under voltage lockout threshold                    | V <sub>CC(UVL)</sub>    | V <sub>CC</sub> falling                         | 3.8   | 4.0   | 4.2   | V    |
| Start-up current                                   | I <sub>IN(ST)</sub>     | V <sub>CC</sub> = 10V                           |       | 1.0   |       | μA   |
| Quiescent current                                  | I <sub>CCQ</sub>        | V <sub>CC</sub> = 14V, without driver switching |       | 2.7   | 4.0   | mA   |
| No-load operating current (Note 1 & 4)             | I <sub>CC_NL</sub>      | No-load operation in DDPWM mode                 |       | 0.25  |       | mA   |



## **6.0 Electrical Characteristics (cont.)**

 $V_{CC}$  = 12V, -40°C  $\leq$  T<sub>A</sub>  $\leq$  85°C, unless otherwise specified (Note 1)

| Parameter   | Symbol           | Test Conditions   | Min | Тур | Max   | Unit |
|---|------------------|---|-----|-----|-------|------|
| BJT Section (Pin 1, Pin 2, and Pin 8)                                   |                  |   |     |     |       |      |
| Collector cutoff current  | I <sub>CB0</sub> | V <sub>CB</sub> = 800V, I <sub>E</sub> = 0A                 |     |     | 0.01  | mA   |
|   |                  | $V_{CE} = 800V, R_{EB} = 0\Omega$<br>$T_{A} = 25^{\circ}C$  |     |     | 0.01  |      |
| Collector-Emitter cutoff current  | I <sub>CES</sub> | $V_{CE} = 800V, R_{EB} = 0\Omega$<br>$T_{A} = 100^{\circ}C$ |     |     | 0.02  | mA   |
|   |                  | $V_{CE} = 500V, R_{EB} = 0\Omega$<br>$T_{A} = 25^{\circ}C$  |     |     | 0.005 |      |
| DC Current Gain (Note 2)  | h <sub>FE</sub>  | $V_{CE} = 5V, I_{C} = 0.2A$                                 | 15  |     | 40    |      |
|   |                  | $V_{CE} = 5V, I_{C} = 0.3A$                                 | 10  |     | 30    |      |
|   |                  | $V_{CE} = 5V$ , $I_C = 1mA$                                 | 10  |     |       |      |
| Collector-Base breakdown voltage  | $V_{CB0}$        | I <sub>C</sub> = 0.1mA                                      | 800 |     |       | V    |
| Collector-Emitter breakdown voltage (Emitter and base shorted together) | V <sub>CES</sub> | $I_C = 1$ mA, $R_{EB} = 0$ Ω                                | 800 |     |       | V    |
| Collector-Emitter sustain voltage                                       | $V_{CEO(SUS)}$   | I <sub>C</sub> = 1mA, L <sub>M</sub> = 25mH                 | 500 |     |       | V    |
| Collector-Emitter saturation voltage (Note 2)                           | $V_{CE(SAT)}$    | I <sub>C</sub> = 0.1A, I <sub>B</sub> = 0.02A               |     | 0.1 | 0.3   | V    |
| PWM switching frequency (Note 3)  | $f_{SW}$         | > 50% load  |     | 72  |       | kHz  |

#### Notes:

Note 1. These parameters are not 100% tested. They are guaranteed by design and characterization.

Note 2. Impulse  $t_P \le 300\mu s$ , duty cycle  $\le 2\%$ .

Note 3: Operating frequency varies based on the load conditions, see Section 9.6 for more details.

Note 4. See Sections 10.6 and 10.7 for details.

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## **8.0 Typical Performance Characteristics**

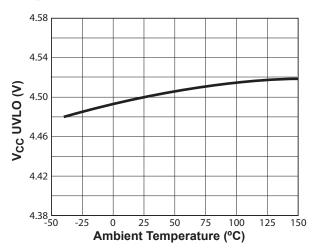


Figure 8.1 :  $V_{CC}$  UVLO vs. Temperature

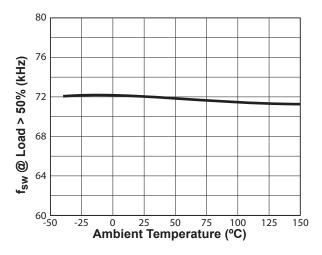


Figure 8.3: Switching Frequency vs. Temperature<sup>1</sup>

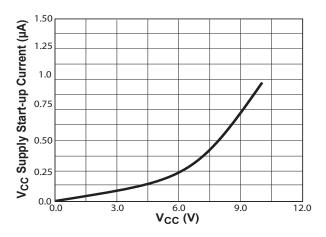


Figure 8.5 :  $V_{CC}$  vs.  $V_{CC}$  Supply Start-up Current



Note 1. Operating frequency varies based on the load conditions, see Section 9.6 for more details.

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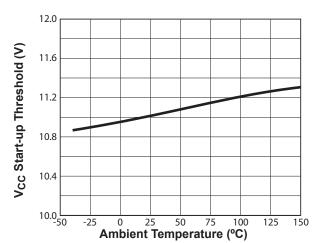


Figure 8.2: Start-Up Threshold vs. Temperature

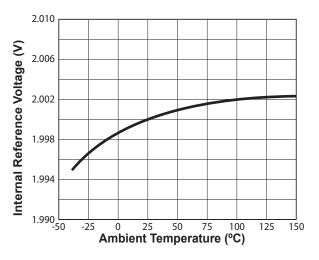


Figure 8.4 : Internal Reference vs. Temperature



## 9.0 Functional Block Diagram

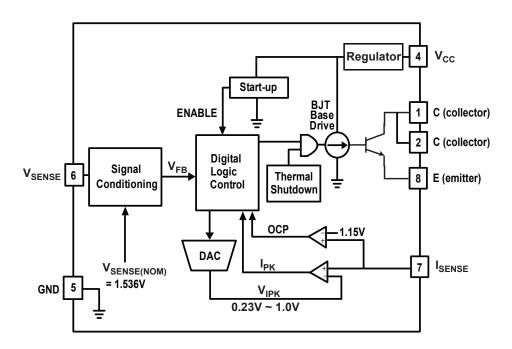


Figure 9.1: CR1511 Functional Block Diagram



### 10.0 Theory of Operation

The CR1511 is a digital controller integrated with a power BJT. It uses a proprietary primary-side control technology to eliminate the opto-isolated feedback and secondary regulation circuits required in traditional designs. This provides a low-cost solution for low power AC/DC adapters. The core PWM processor uses fixed-frequency Discontinuous Conduction Mode (DCM) operation at higher power levels and switches to variable frequency operation at light loads to maximize efficiency. Furthermore, iWatt's digital control technology enables fast dynamic response, tight output regulation, and full-featured circuit protection with primary-side control.

The block diagram in Figure 9.1 shows the digital logic control block generates the switching on-time and off-time information based on the output voltage and current feedback signal and provides instructions to dynamically control the internal BJT base current. The I<sub>SENSE</sub> is an analog input configured to sense the primary current in a voltage form. In order to achieve the peak current mode control and cycle-by-cycle current limit, the V<sub>IPK</sub> sets the threshold for the I<sub>SENSE</sub> to compare with, and it varies in the range of 0.23V (typical) and 1.00V (typical) under different line and load conditions. The system loop is automatically compensated internally by a digital error amplifier. Adequate system phase margin and gain margin are guaranteed by design and no external analog components are required for loop compensation. The CR1511 uses an advanced digital control algorithm to reduce system design time and increase reliability.

Furthermore, accurate secondary constant-current operation is achieved without the need for any secondary-side sense and control circuits.

The CR1511 uses adaptive multi-mode PWM/PFM control to dynamically change the BJT switching frequency for efficiency, EMI, and power consumption optimization. In addition, it achieves unique BJT quasi-resonant switching to further improve efficiency and reduce EMI. The built-in single-point fault protection features include over-voltage protection (OVP), output-short-circuit protection (SCP), over-current protection (OCP), and ISENSE fault detection.

Dialog's digital control scheme is specifically designed to address the challenges and trade-offs of power conversion design. This innovative technology is ideal for balancing new regulatory requirements for green mode operation with more practical design considerations such as the lowest possible cost, smallest size and high performance output control.

#### 10.1 Pin Detail

#### Pin 1 and Pin 2 - C

Collector pin of the internal power BJT.

### Pin 4 - V<sub>cc</sub>

Power supply for the controller during normal operation. The controller will start up when  $V_{\text{CC}}$  reaches 11.0V (typical) and will shut-down when the  $V_{\text{CC}}$  voltage is 4.0V (typical). A decoupling capacitor should be connected between the  $V_{\text{CC}}$  pin and GND.

#### Pin 5 - GND

Ground.

#### Pin 6 - V<sub>SENSE</sub>

Sense signal input from auxiliary winding. This provides the secondary voltage feedback used for output regulation.

#### Pin 7 – I<sub>SENSE</sub>

Primary current sense. It is used for cycle-by-cycle peak current control and limit.

#### Pin 8 – E

Emitter pin of the internal power BJT. This pin must be shorted to pin 7 (the  $I_{SENSE}$  pin).

#### 10.2 Start-up

Prior to start-up, the  $V_{CC}$  pin is charged typically through start-up resistors. When  $V_{CC}$  bypass capacitor is fully charged to a voltage higher than the start-up threshold  $V_{CC(ST)}$ , the ENABLE signal becomes active to enable the control logic, and the CR1511 begins to perform initial over-temperature protection check. When the internal die junction temperature is below 100°C, the CR1511 commences soft-start function. During this start-up process, an adaptive soft-start control algorithm is applied, during which the initial output pulses are small and gradually become larger until the full pulse width is achieved. The peak current is limited cycle by cycle by the  $I_{PEAK}$  comparator.

If at any time the  $V_{\text{CC}}$  voltage drops below  $V_{\text{CC(UVL)}}$  threshold then all the digital logic is reset. At this time the ENABLE signal becomes low and the  $V_{\text{CC}}$  capacitor is charged up again towards the start-up threshold.





Start-up Sequencing

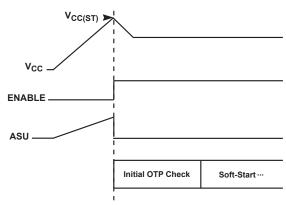


Figure 10.1: Start-up Sequencing Diagram

### 10.3 Understand Primary Feedback

Figure 9.2 illustrates a simplified flyback converter. When the switch Q1 conducts during  $t_{\text{ON(t)}},$  the current  $i_g(t)$  is directly drawn from rectified  $v_g(t).$  The energy  $E_g(t)$  is stored in the magnetizing inductance  $L_{\text{M}}.$  The rectifying diode D1. is reverse biased and the load current  $I_{\text{O}}$  is supplied by the secondary capacitor  $C_{\text{O}}.$  When Q1 turns off, D1 conducts and the stored energy  $E_g(t)$  is delivered to the output.

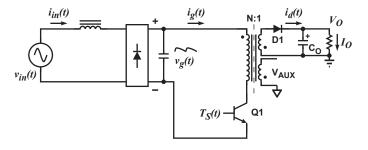


Figure 10.2: Simplified Flyback Converter

To tightly regulate the output voltage, the information about the output voltage and load current must be accurately sensed. In the DCM Flyback converter, this information can be read via the auxiliary winding or the primary magnetizing inductance ( $L_M$ ). During the Q1 on-time, the load current is supplied from the output filter capacitor  $C_O$ . The voltage across  $L_M$  is  $v_g(t)$ , assuming the voltage dropped across Q1 is zero. The current in Q1 ramps up linearly at a rate of:

$$\frac{di_{g}(t)}{dt} = \frac{v_{g}(t)}{L_{M}} \tag{9.1}$$

At the end of on-time, the current has ramped up to:

$$i_{g\_peak}(t) = \frac{v_g(t) \times t_{ON}}{L_M}$$
(9.2)

This current represents a stored energy of:

$$E_{g} = \frac{L_{M}}{2} \times i_{g\_peak} \left(t\right)^{2} \tag{9.3}$$

When Q1 turns off at  $t_{\rm O}$ ,  $i_{\rm g}(t)$  in  $L_{\rm M}$  forces a reversal of polarities on all windings. Ignoring the communication-time caused by the leakage inductance LK at the instant of turn-off  $t_{\rm O}$ , the primary current transfers to the secondary at a peak amplitude of:

$$i_d(t) = \frac{N_P}{N_S} \times i_{g\_peak}(t) \tag{9.4}$$

Assuming the secondary winding is master, and the auxiliary winding is slave,

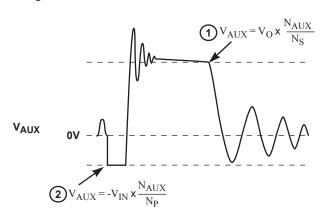


Figure 10.3: Auxiliary Voltage Waveforms

The auxiliary voltage is given by:

$$V_{AUX} = \frac{N_{AUX}}{N_S} (V_O + \Delta V) \tag{9.5}$$

and reflects the output voltage as shown in Figure 9.3.

The voltage at the load differs from the secondary voltage by a diode drop and IR losses. If the secondary voltage is always read at a constant secondary current, the difference between the output voltage and the secondary voltage is a fixed  $\Delta V.$  If the voltage can be read when the secondary current is small,  $\Delta V$  is also small. With the CR1511,  $\Delta V$  can be ignored.

The real-time waveform analyzer in the CR1511 reads this information cycle by cycle. The part then generates a feedback voltage  $V_{\text{FB}}$ . The  $V_{\text{FB}}$  signal precisely represents

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the output voltage under most conditions and is used to regulate the output voltage.

### **10.4 Constant Voltage Operation**

After soft-start has been completed, the digital control block measures the output conditions. It determines output power levels and adjusts the control system according to a light load or heavy load. If this is in the normal range, the device operates in the constant voltage (CV) mode, and changes the pulse width ( $T_{\text{ON}}$ ) and off time ( $T_{\text{OFF}}$ ) to meet the output voltage regulation requirements.

If no voltage is detected on  $V_{\text{SENSE}}$  it is assumed that the auxiliary winding of the transformer is either open or shorted and the CR1511 shuts down.

### 10.5 Constant Current Operation

The constant current (CC) mode is useful in battery charging applications. During this mode of operation the CR1511 regulates the output current at a constant level regardless of the output voltage, while avoiding continuous conduction mode.

To achieve this regulation the CR1511 senses the load current indirectly through the primary current. The primary current is detected by the  $I_{\text{SENSE}}$  pin through a resistor from the BJT emitter to ground. The power supply output CC limit current is determined by the transformer turns ratio and current sense resistor, given by

$$I_{O\_CC} = 0.211 \frac{N}{R_S} \eta_X$$
 (9.6)

where N is the transformer primary to secondary side winding turns ratio,  $R_S$  is the current sense resistor, and  $\eta_X$  is the transformer conversion efficiency.

When operating in the CC mode, with the decrease of equivalent load resistance or battery voltage, both the output voltage and  $V_{\rm CC}$  decrease. Once the  $V_{\rm CC}$  voltage is below UVLO threshold the CR1511 shuts down (see Section 9.10). Meanwhile, the CR1511 monitors the output voltage, and shuts down the system when the detected output voltage is lower than a certain level; this is known as the "CC shutdown voltage". The actual shutdown can occur under either one of the above two conditions.

The CR1511 provides 3.0V "CC shutdown voltage". The "CC shutdown voltage" here refers to the voltage at the cable end, and the actual output voltage at the PCB end is the sum of the "CC shutdown voltage" and the "Cable Comp" (specified in Section 9.13). Similar to the "Cable Comp", the "CC shutdown voltage" is also specified based on the nominal

output voltage of 5V. For different output voltage, the actual "CC shutdown voltage" needs to be scaled accordingly. As a result, the "CC shutdown voltage" option can adaptively match the cable voltage drop at CC mode. For instance, for a 5V/1A charger design, if the cable resistance is around 150m $\Omega$ , the voltage drop across the cable is around 150mV under both the CV mode full load and CC mode conditions. If CDC Comp is zero, at CV full load, the voltage at the PCB end is around 5V, and the voltage at the cable end is around 4.85V. Then the CC shutdown occurs when the voltage at the PCB end decreases to 3.0V, and the voltage at the cable end deceases to 2.85V. Normally a product option with CDC Comp is needed in this design in order to achieve a desirable voltage regulation at CV mode, e.g., the CDC Comp production option is selected as 150mV. Then at CV full load, the voltage at the PCB end is around 5.15V, and the voltage at the cable end is around 5V. Correspondingly the CC shutdown occurs when the voltage at the PCB end decreases to 3.15V, and the voltage at the cable end deceases to 3.0V.

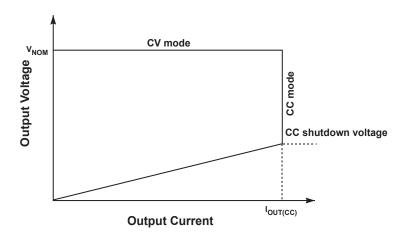


Figure 10.4: Power Envelop

# 10.6 Multi-Mode PWM/PFM Control and Quasi-Resonant Switching

The CR1511 uses a proprietary adaptive multi-mode PWM / PFM control to dramatically improve the light-load efficiency and thus the overall average efficiency.

During the constant voltage (CV) operation, the CR1511 normally operates in a pulse-width-modulation (PWM) mode during heavy load conditions. In the PWM mode, the switching frequency keeps around constant. As the output load  $I_{\text{OUT}}$  is reduced, the on-time  $t_{\text{ON}}$  is decreased, and the controller adaptively transitions to a pulse-frequency-modulation (PFM) mode. During the PFM mode, the BJT is switched on for a set duration under a given instantaneous rectified AC input voltage, but its off-time is modulated by

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the load current. With a decreasing load current, the off-time increases and the switching frequency decreases.

When the switching frequency approaches to human ear audio band, the CR1511 transitions to a second level of PWM mode, namely deep PWM mode (DPWM). During the DPWM mode, the switching frequency keeps around 25kHz to avoid audible noise. As the load current is further reduced, the CR1511 transitions to a second level of PFM mode, namely deep PFM mode (DPFM), which can reduce the switching frequency to a low level. Although the switching frequency drops across the audible frequency range during the DPFM mode, the output current in the power converter has reduced to an insignificant level in the DPWM mode before transitioning to the DPFM mode. The power converter produces no audible noise, while achieving high efficiency across varying load conditions.

As the load current reduces to low or no-load condition, the CR1511 transitions from the DPFM to the third level of PWM mode, namely deep-deep PWM mode (DDPWM), where the switching frequency is fixed at around 2.1kHz.

The CR1511 also incorporates a unique proprietary quasiresonant switching scheme that achieves valley-mode turn on for every PWM/PFM switching cycle, during all PFM and PWM modes and in both CV and CC operations. This unique feature greatly reduces the switching loss and dv/dt across the entire operating range of the power supply. Due to the nature of quasi-resonant switching, the switching frequency can vary slightly cycle by cycle, providing the additional benefit of reducing EMI. Together these innovative digital control architecture and algorithms enable the CR1511 to achieve highest overall efficiency and lowest EMI, without causing audible noise over entire operating range.

# 10.7 Less Than 30mW No-Load Power with Fast Load Transient Response

The CR1511 features the distinctive DDPWM control at no-load conditions to help achieve low no-load power consumption (< 30mW for typical applications) and meanwhile to ensure fast dynamic load response. The power supply system designs including the pre-load resistor selection should ensure the power supply can stably operate in the DDPWM mode at the steady-state no-load condition. If the pre-load resistor is too small, the no-load power consumption increases; on the other hand, if it is too large, the output voltage may increase and even cause overvoltage since the switching frequency is fixed at around 2.1kHz. For typical designs, the pre-load resistor is in the range of  $5k\Omega$  to  $8k\Omega$ .

Aside from the appropriate use of pre-load resistor, the CR1511 enjoys a few other features to bring down no-load

power consumption as well. First, the CR1511 implements an intelligent low-power management technique that achieves ultra-low chip operating current at no-load (typically around 250µA). Second, the use of the power switch of BJT instead of MOSFET requires a lower driving voltage, enabling a low UVLO threshold (typically 4.0V). The power supply system design can fully use this low UVLO feature to have a low V<sub>CC</sub> voltage at the no-load operation in order to minimize the no-load power. In addition, the ultra-low start-up current during the ramp-up of V<sub>CC</sub> towards the start-up threshold  $V_{CC(ST)}$  (see Figure 7.5), allows for the use of high resistance start-up resistors to minimize their loss while still retaining reasonable turn-on time. All together these features ensure that with the lowest system cost power supplies built with the CR1511 can achieve less than 30mW no-load power consumption at 230V<sub>AC</sub> input and very tight constant voltage and constant current regulation over the entire operating range including the no-load operation.

While achieving low no-load power consumption, the CR1511 implements innovative proprietary digital control technology to intelligently detect any load transient events, and achieve fast dynamic load response for both one-time and repetitive load transients. In particular, for load transients that are demanded in some applications as from absolutely no load to full load, the CR1511 can still guarantee a fast enough response to meet the most stringent requirements, with the no-load operating frequency designed at around 2.1kHz

### **10.8 Variable Frequency Operation Mode**

At each of the switching cycles, the falling edge of  $V_{\text{SENSE}}$  is checked. If the falling edge of  $V_{\text{SENSE}}$  is not detected, the off-time is extended until the falling edge of  $V_{\text{SENSE}}$  is detected. The maximum allowed transformer reset time is 110 $\mu$ s. When the transformer reset time reaches 110 $\mu$ s, the CR1511 shuts off.

### **10.9 Internal Loop Compensation**

The CR1511 incorporates an internal Digital Error Amplifier with no requirement for external loop compensation. For a typical power supply design, the loop stability is guaranteed to provide at least 45 degrees of phase margin and -20dB of gain margin.

## 10.10 Voltage Protection Features

The secondary maximum output DC voltage is limited by the CR1511. When the  $V_{\text{SENSE}}$  signal exceeds the output OVP threshold at point 1 shown in Figure 9.3, the CR1511 shuts down.

Although there is no pin available to directly sense the input voltage, the CR1511 uses an innovative proprietary digital

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control method to detect and analyze the switch ON time. which provides real-time indirect sensing and monitoring of the magnitude and shape of the DC bulk capacitor voltage. This enables the CR1511 to determine and distinguish various conditions of the AC input voltage such as brownout, brown-in and unplug, and to take appropriate actions. When the AC input voltage drops to below normal operation range and the power supply input is still connected to the AC source, the CR1511 initiates brown-out protection and shuts down the power supply adaptively according to the power supply load condition. Meanwhile, a brown-in input voltage threshold is set with hysteresis. In the case of the power supply input being unplugged or disconnected from the AC source, the CR1511 continues to control the switching actions to discharge the DC bulk capacitor voltage to a safe level before shutting down the power supply. Also, the CR1511 monitors the voltage on the V<sub>CC</sub> pin and when the voltage on this pin is below UVLO threshold the IC shuts down immediately.

When any of these faults are met the IC remains biased to discharge the  $V_{\text{CC}}$  supply. Once  $V_{\text{CC}}$  drops below UVLO threshold, the controller resets itself and then initiates a new soft-start cycle. The controller continues attempting start up until the fault condition is removed.

### 10.11 PCL, OCP and SRS Protection

Peak-current limit (PCL), (OCP), and sense-resistor short protection (SRSP) are features built-in to the CR1511. With the  $I_{\rm SENSE}$  pin the CR1511 is able to monitor the peak primary current. This allows for cycle by cycle peak current control and limit. When the primary peak current multiplied by the  $I_{\rm SENSE}$  resistor is greater than 1.15V, over current (OCP) is detected and the IC immediately turns off the base driver until the next cycle. The output driver sends out a switching pulse in the next cycle, and the switching pulse continues if the OCP threshold is not reached; or, the switching pulse turns off again if the OCP threshold is reached. If the OCP occurs for several consecutive switching cycles, the CR1511 shuts down.

If the  $I_{\text{SENSE}}$  resistor is shorted, a potential danger of the over current condition not being detected exists. Thus, the IC is designed to detect this sense-resistor-short fault during startup and shut down immediately. The  $V_{\text{CC}}$  is discharged since the IC remains biased. Once  $V_{\text{CC}}$  drops below the UVLO threshold, the controller resets itself and then initiates a new soft-start cycle. The controller continues attempting to startup, but does not fully startup until the fault condition is removed.

### **10.12 Dynamic Base Current Control**

One important feature of the CR1511 is that it directly drives a BJT switching device with dynamic base current control to optimize performance. The BJT base current ranges from 13mA to 40mA, and is dynamically controlled according to the power supply load change. The higher the output power, the higher the base current. Specifically, the base current is related to  $V_{\text{IPK}}$ .

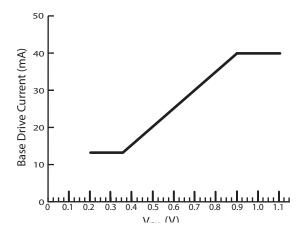


Figure 10.5 : Base Drive Current vs V<sub>IPK</sub>

### **10.13 Cable Drop Compensation**

The CR1511 incorporates an innovative method to compensate for any IR drop in the secondary circuit including cable and cable connector. A 2.5W adapter with 5V DC output has 3% deviation at 0.5A load current due to the drop across a 24 AWG, 1.8 meter DC cable without cable compensation. The CR1511 compensates for this voltage drop by providing a voltage offset to the feedback signal based on the amount of load current detected.

The "Cable Comp" is specified based on the nominal output voltage of 5V with the assumption that the secondary diode voltage drop can be ignored at the point when the secondary voltage is sensed. For different output voltage, the actual voltage increment needs to be scaled accordingly.

To calculate the amount of cable compensation needed, take the resistance of the cable and connector and multiply by the maximum output current.

## 10.14 Hiccup/Auto-Restart Mode

If an CR1511-based power supply shuts down during any fault condition, the CR1511 automatically re-starts and goes through the soft-start cycle. In case of a persistent fault condition, the IC continues to go through a shutdown and re-start cycle. This mode of operation is often called a hiccup mode or auto-restart mode. During a hiccup/auto-restart

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mode, the power dissipation of the power supply is very low due to short on-time and long off-time. Fault conditions that can cause hiccup mode operation include:

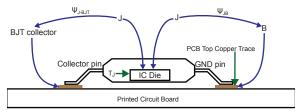
- V<sub>CC</sub> voltage dropping below V<sub>CC(UVL)</sub> threshold
- Output voltage dropping below CC shutdown voltage threshold.
- ISENSE over-current protection (OCP)
- Output short circuit
- Current sense resistor short circuit before startup
- Over-voltage protection (OVP)
- Brown-out protection

#### 10.15 Internal OTP

The CR1511 features an internal OTP that shuts down the device if the internal die junction temperature reaches above 150°C (typical). The device is kept off until the junction temperature drops below 100°C (typical), when the device initiates a new soft-start process to build up the output voltage.

### 10.16 Thermal Design

The CR1511 may be installed inside a small enclosure, where space and air volumes are constrained. Under these circumstances  $\theta_{JA}$  (thermal resistance, junction-to-ambient) measurements do not provide useful information for this type of application. Hence we have also provided  $\psi_{JB}$  which estimates the increase in die junction temperature relative to the PCB surface temperature. Figure 9.6 shows the PCB surface temperature is measured at the IC's GND pin pad.



Note: For illustrative purposes only does not represent a correct pinout or size of chip

Figure 10.6: Thermal Resistance

The actual IC power dissipation is related to the power supply application circuit, component selection and operation conditions. The maximum IC power dissipation should be used to estimate the maximum junction temperature. For a typical 3-W power supply, the power dissipation can be around 500mW.

The output power table in Section 3.0 recommends maximum practical continuous output power level be achieved under the following conditions:

- Typical 5V-output power supply designs with a Schottky rectifier diode
- Ambient temperature of 50°C for open frame and adapter enclosure internal temperature of 60°C in a nonventilated environment
- AC Input voltage is 85V<sub>AC</sub> at 47Hz
- Minimum bulk capacitor voltage is 90V for open frame and 70V for adapter
- The CR1511 device is mounted on PCB with no special enhancement for heatsinking and the emitter pin temperature is kept below 90°C

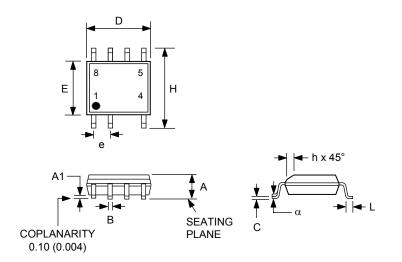
Under a given power dissipation, reducing the GND, emitter, and collector pin temperature reduces the junction temperature. Generally, increasing the PCB area and associated amount of copper trace reduces the junction temperature. In particular, the power BJT is a power source and therefore the PCB plating area attached to the two collector pins and the emitter pin can be reasonably large to gain the thermal benefits without violating the high voltage creepage requirements if higher output power is desired. Higher output power is also achievable if bulk capacitor voltage is higher, design is for high line only, design components temperature restriction limit is higher, ambient temperature is lower, or extra metal piece/heat spreader is attached to related pins or package.





## **11.0 Physical Dimensions**

#### 7-Lead Small Outline (SOIC) Package



| Symbol | Inc   | Inches |           | eters |
|--------|-------|--------|-----------|-------|
| Syr    | MIN   | MAX    | MIN       | MAX   |
| Α      | 0.060 | 0.068  | 1.52      | 1.73  |
| A1     | 0.004 | 0.008  | 0.10      | 0.20  |
| В      | 0.014 | 0.018  | 0.36      | 0.46  |
| С      | 0.007 | 0.010  | 0.18      | 0.25  |
| D      | 0.188 | 0.197  | 4.78      | 5.00  |
| Е      | 0.150 | 0.157  | 3.81      | 3.99  |
| е      | 0.050 | BSC    | 1.270 BSC |       |
| Н      | 0.230 | 0.244  | 5.84      | 6.20  |
| h      | 0.010 | 0.016  | 0.25      | 0.41  |
| L      | 0.023 | 0.029  | 0.58      | 0.74  |
| α      | 0°    | 8°     |           |       |

Compliant to JEDEC Standard MS12F

Controlling dimensions are in inches; millimeter dimensions are for reference only

This product is RoHS compliant and Halide free.

Soldering Temperature Resistance:

- [a] Package is IPC/JEDEC Std 020D Moisture Sensitivity Level 1
- [b] Package exceeds JEDEC Std No. 22-A111 for Solder Immersion Resistance; package can withstand 10 s immersion < 260°C

Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25 mm per side.

The package top may be smaller than the package bottom. Dimensions D and E1 are determined at the outermost extremes of the plastic bocy exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.

## **12.0 Ordering Information**

| Part Number | Options                                      | Package | Description              |
|-------------|--|---------|--------------------------|
| CR1511-30   | Cable Comp = 150mV, CC shutdown voltage = 3V | SOIC-7  | Tape & Reel <sup>1</sup> |
| CR1511-36   | Cable Comp = 0mV, CC shutdown voltage = 3V   | SOIC-7  | Tape & Reel <sup>1</sup> |

Note 1: Tape & Reel packing quantity is 2,500/reel. Minimum ordering quantity is 2,500.



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